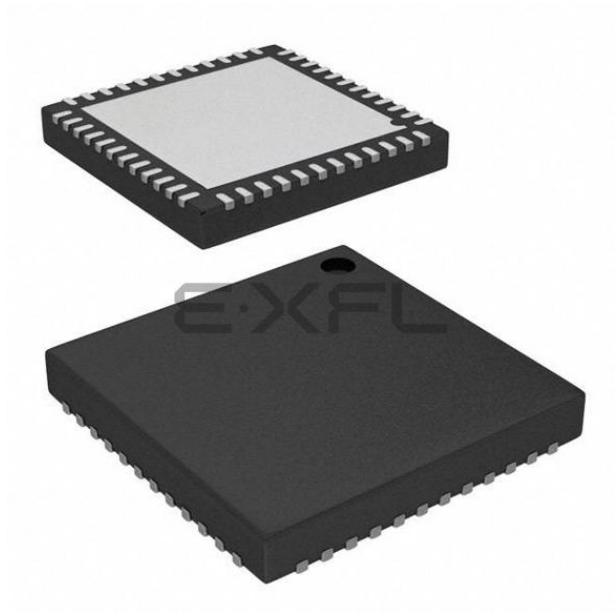

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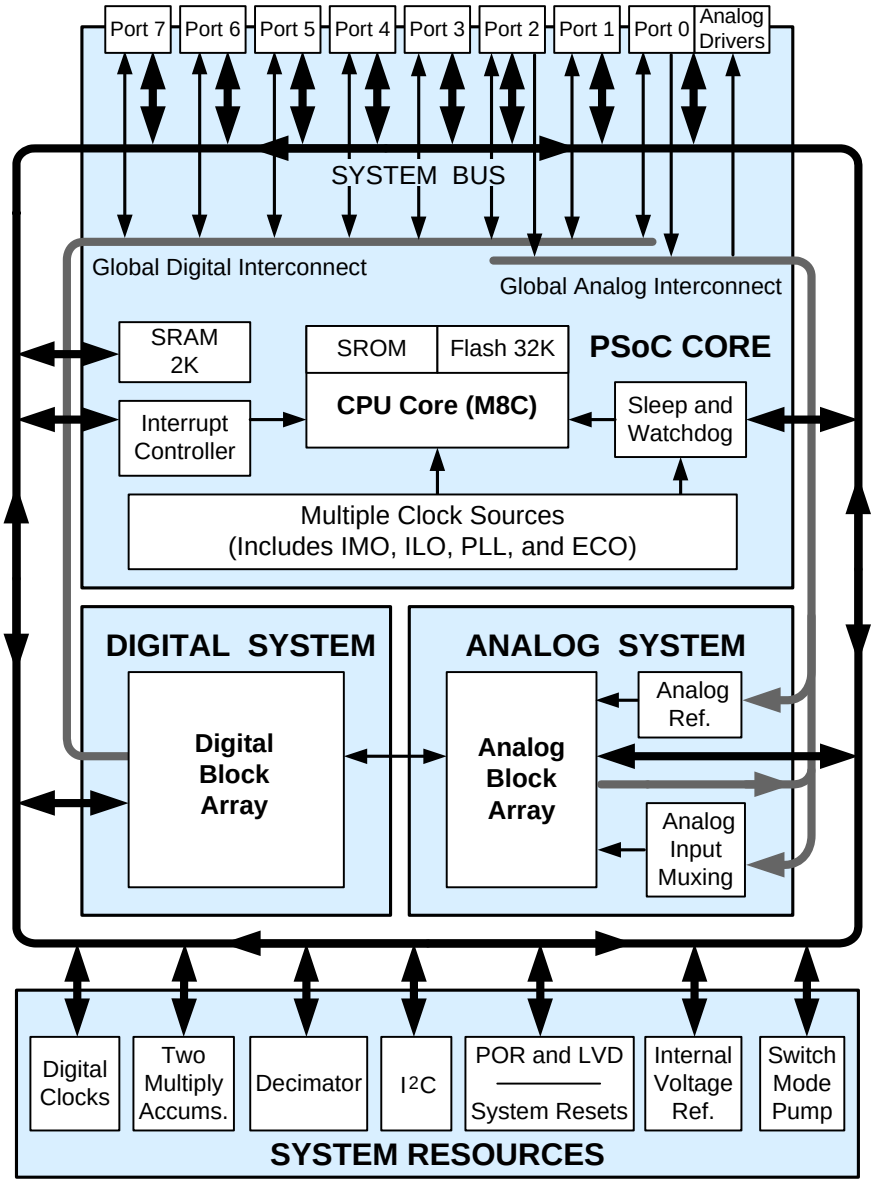
What Are Embedded - Microcontrollers - Application Specific?

Application-specific microcontrollers are engineered to

Details	
Product Status	Obsolete
Applications	HB LED Controller
Core Processor	M8C
Program Memory Type	FLASH (32KB)
Controller Series	CY8CLED
RAM Size	2K x 8
Interface	I²C, SPI, UART/USART
Number of I/O	44
Voltage - Supply	3V ~ 5.25V
Operating Temperature	-40°C ~ 85°C
Mounting Type	Surface Mount
Package / Case	48-VFQFN Exposed Pad
Supplier Device Package	48-QFN (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8cled16-48lfxit

Logic Block Diagram



Contents

EZ-Color™ Functional Overview

Cypress's EZ-Color family of devices offers the ideal control solution for High Brightness LED applications requiring intelligent dimming control. EZ-Color devices combine the power and flexibility of Programmable System-on-Chip (PSoC); with Cypress's precise illumination signal modulation (PrISM) modulation technology providing lighting designers a fully customizable and integrated lighting solution platform.

The EZ-Color family supports a range of independent LED channels from 4 channels at 32 bits of resolution each, up to 16 channels at 8 bits of resolution each. This enables lighting designers the flexibility to choose the LED array size and color quality. PSoC Designer software, with lighting specific drivers, can significantly cut development time and simplify implementation of fixed color points through temperature, optical, and LED binning compensation. EZ-Color's virtually limitless analog and digital customization allow for simple integration of features in addition to intelligent lighting, such as Battery Charging, Image Stabilization, and Motor Control during the development process. These features, along with Cypress' best-in-class quality and design support, make EZ-Color the ideal choice for intelligent HB LED control applications.

Target Applications

- LCD Backlight
- Large Signs
- General Lighting
- Architectural Lighting
- Camera/Cell Phone flash
- flashlights

The PSoC Core

The PSoC core is a powerful engine that supports a rich feature set. The core includes a central processing unit (CPU), memory, clocks, and configurable general purpose I/O (GPIO).

The M8C CPU core is a powerful processor with speeds up to 48 MHz, providing a four million instructions per second (MIPS) 8-bit Harvard-architecture microprocessor. The CPU utilizes an interrupt controller with 25 vectors, to simplify programming of real time embedded events. Program execution is timed and protected using the included Sleep and watchdog timers (WDT).

Memory encompasses 32 KB of flash for program storage, 2 KB of SRAM for data storage, and up to 2 KB of EEPROM emulated using the flash. Program flash utilizes four protection levels on blocks of 64 bytes, allowing customized software IP protection.

The EZ-Color family incorporates flexible internal clock generators, including a 24 MHz internal main oscillator (IMO) accurate to 2.5% over temperature and voltage. The 24 MHz IMO can also be doubled to 48 MHz for use by the digital system. A low power 32 kHz internal low speed oscillator (ILO) is provided for the Sleep timer and WDT. If crystal accuracy is desired, the 32.768 kHz external crystal oscillator (ECO) is available for use as a real time clock (RTC) and can optionally generate a crystal-accurate 24 MHz system clock using a PLL. The clocks, together with programmable clock dividers (as a System Resource), provide the flexibility to integrate almost any timing requirement into the EZ-Color device.

EZ-Color GPIOs provide connection to the CPU, digital and analog resources of the device. Each pin's drive mode may be selected from eight options, allowing great flexibility in external interfacing. Every pin also has the capability to generate a system interrupt on high level, low level, and change from last read.

The Digital System

The digital system is composed of 16 digital PSoC blocks. Each block is an 8-bit resource that can be used alone or combined with other blocks to form 8, 16, 24, and 32-bit peripherals, which are called user modules. Digital peripheral configurations include those listed below.

- PrISM (8-to 32-bit)
- PWMs (8-to 32-bit)
- PWMs with Dead band (8-to 32-bit)
- Counters (8-to 32-bit)
- Timers (8-to 32-bit)
- UART 8 bit with selectable parity (up to 4)
- SPI master and slave (up to 4 each)
- I^2C slave and multi-master (1 available as a System Resource)
- Cyclical Redundancy Checker/Generator (8- to 32-bit)
- IrDA (up to 4)
- Generators (8-to 32-bit)

The digital blocks can be connected to any GPIO through a series of global buses that can route any signal to any pin. The buses also allow for signal multiplexing and for performing logic operations. This configurability frees your designs from the constraints of a fixed peripheral controller.

Digital blocks are provided in rows of four, where the number of blocks varies by EZ-Color device family. This allows you the optimum choice of system resources for your application. Family resources are shown in Table 1 on page 6.

DC GPIO Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and -40 °C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 7. DC GPIO Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
R_{PU}	Pull-up Resistor	4	5.6	8	kΩ	
R_{PD}	Pull-down Resistor	4	5.6	8	kΩ	
V_{OH}	High output level	V_{DD} - 1.0	–	–	V	IOH = 10 mA, V_{DD} = 4.75 to 5.25 V (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])). 80 mA maximum combined IOH budget.
V_{OL}	Low output level	–	–	0.75	V	IOL = 25 mA, V_{DD} = 4.75 to 5.25 V (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])). 150 mA maximum combined IOL budget.
I_{OH}	High level source current	10	–	–	mA	VOH = V_{DD}-1.0 V. See the limitations of the total current in the Note for VOH.
I_{OL}	Low level sink current	25	–	–	mA	VOL = 0.75 V. See the limitations of the total current in the Note for VOL.
V_{IL}	Input low level	–	–	0.8	V	V_{DD} = 3.0 to 5.25.
V_{IH}	Input high level	2.1	–		V	V_{DD} = 3.0 to 5.25.
V_H	Input hysterisis	–	60	–	mV	
I_{IL}	Input leakage (Absolute Value)	–	1	–	nA	Gross tested to 1 μA.
C_{IN}	Capacitive load on pins as input	–	3.5	10	pF	Package and pin dependent. Temp = 25 °C.
C_{OUT}	Capacitive load on pins as output	–	3.5	10	pF	Package and pin dependent. Temp =25 °C.

Table 9. 3.3-V DC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
V_{OSOA}	Input offset voltage (absolute value) Power = Low, Opamp bias = Low Power = Low, Opamp bias = High Power = Medium, Opamp bias = Low Power = Medium, Opamp bias = High Power = High, Opamp bias = Low Power = High, Opamp bias = High	 – – – – – –	 1.4 1.4 1.4 1.4 1.4 –	 10 10 10 10 10 –	 mV mV mV mV mV mV	Power = High, Opamp bias = High setting is not allowed for 3.3 V V_{DD} operation.
TCV_{OSOA}	Average input offset voltage drift	–	7	40	µV/°C	–
I_{EBOA}	Input leakage current (port 0 analog pins)	–	200	–	pA	Gross tested to 1 µA.
C_{INOA}	Input capacitance (port 0 analog pins)	–	4.5	9.5	pF	Package and pin dependent. Temp = 25 °C
V_{CMOA}	Common mode voltage range	0	–	V_{DD}	V	The common-mode input voltage range is measured through an analog output buffer. The specification includes the limitations imposed by the characteristics of the analog output buffer.
$CMRR_{OA}$	Common mode rejection ratio	60	–	–	dB	–
G_{OLOA}	Open loop gain	80	–	–	dB	–
$V_{OHIGHOA}$	High output voltage swing (internal signals)	V_{DD} – 0.01	–	–	V	–
V_{OLOWOA}	Low output voltage swing (internal signals)	–	–	0.01	V	–
I_{SOA}	Supply current (including associated AGND buffer) Power = Low, Opamp bias = Low Power = Low, Opamp bias = High Power = Medium, Opamp bias = Low Power = Medium, Opamp bias = High Power = High, Opamp bias = Low Power = High, Opamp bias = High	 – – – – – –	 150 300 600 1200 2400 –	 200 400 800 1600 3200 –	 µA µA µA µA µA µA	Power = High, Opamp bias = High setting is not allowed for 3.3 V V_{DD} operation.
$PSRR_{OA}$	Supply voltage rejection ratio	54	80	–	dB	$V_{SS} \le V_{IN} \le (V_{DD} – 2.25)$ or $(V_{DD} – 1.25\ V) \le V_{IN} \le V_{DD}$

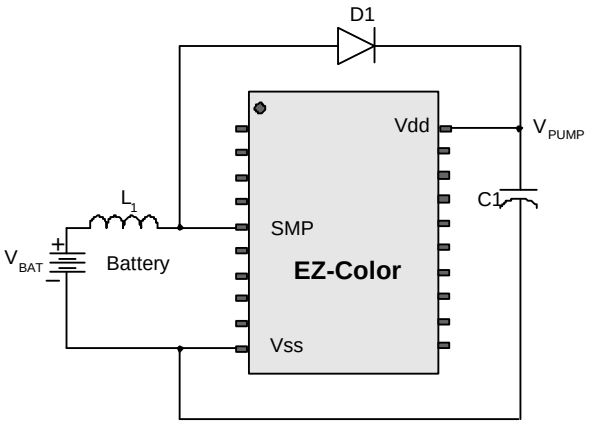
DC Low Power Comparator Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and -40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V at 25 °C and are for design guidance only.

Table 10. DC Low Power Comparator Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{REFLPC}	Low power comparator (LPC) reference voltage range	0.2	–	V_{DD} - 1	V	–
I_{SLPC}	LPC supply current	–	10	40	µA	–
V_{OSLPC}	LPC voltage offset	–	2.5	30	mV	–

Figure 6. Basic Switch Mode Pump Circuit



DC Analog Reference Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

The guaranteed specifications are measured through the analog continuous time PSoC blocks. The power levels for AGND refer to the power of the Analog Continuous Time PSoC block. The power levels for RefHi and RefLo refer to the analog reference control register. The limits stated for AGND include the offset error of the AGND buffer local to the Analog Continuous Time PSoC block. Reference control power is high.

Table 14. 5-V DC Analog Reference Specifications

Reference ARF_CR[5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Unit
0b000	RefPower = High Opamp bias = High	V_{REFHI}	Ref High	$V_{DD}/2$ + Bandgap	$V_{DD}/2$ + 1.228	$V_{DD}/2$ + 1.290	$V_{DD}/2$ + 1.352	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.078	$V_{DD}/2$ – 0.007	$V_{DD}/2$ + 0.063	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – Bandgap	$V_{DD}/2$ – 1.336	$V_{DD}/2$ – 1.295	$V_{DD}/2$ – 1.250	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref High	$V_{DD}/2$ + Bandgap	$V_{DD}/2$ + 1.224	$V_{DD}/2$ + 1.293	$V_{DD}/2$ + 1.356	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.056	$V_{DD}/2$ – 0.005	$V_{DD}/2$ + 0.043	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – Bandgap	$V_{DD}/2$ – 1.338	$V_{DD}/2$ – 1.298	$V_{DD}/2$ – 1.255	V
	RefPower = Med Opamp bias = High	V_{REFHI}	Ref High	$V_{DD}/2$ + Bandgap	$V_{DD}/2$ + 1.226	$V_{DD}/2$ + 1.293	$V_{DD}/2$ + 1.356	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.057	$V_{DD}/2$ – 0.006	$V_{DD}/2$ + 0.044	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – Bandgap	$V_{DD}/2$ – 1.337	$V_{DD}/2$ – 1.298	$V_{DD}/2$ – 1.256	V
	RefPower = Med Opamp bias = Low	V_{REFHI}	Ref High	$V_{DD}/2$ + Bandgap	$V_{DD}/2$ + 1.226	$V_{DD}/2$ + 1.294	$V_{DD}/2$ + 1.359	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.047	$V_{DD}/2$ – 0.004	$V_{DD}/2$ + 0.035	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – Bandgap	$V_{DD}/2$ – 1.338	$V_{DD}/2$ – 1.299	$V_{DD}/2$ – 1.258	V

Table 14. 5-V DC Analog Reference Specifications (continued)

Reference ARF_CR[5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Unit
0b011	RefPower = High Opamp bias = High	V_{REFHI}	Ref High	3 × Bandgap	3.788	3.891	3.986	V
		V_{AGND}	AGND	2 × Bandgap	2.500	2.604	3.699	V
		V_{REFLO}	Ref Low	Bandgap	1.257	1.306	1.359	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref High	3 × Bandgap	3.792	3.893	3.982	V
		V_{AGND}	AGND	2 × Bandgap	2.518	2.602	2.692	V
		V_{REFLO}	Ref Low	Bandgap	1.256	1.302	1.354	V
	RefPower = Med Opamp bias = High	V_{REFHI}	Ref High	3 × Bandgap	3.795	3.894	3.993	V
		V_{AGND}	AGND	2 × Bandgap	2.516	2.603	2.698	V
		V_{REFLO}	Ref Low	Bandgap	1.256	1.303	1.353	V
	RefPower = Med Opamp bias = Low	V_{REFHI}	Ref High	3 × Bandgap	3.792	3.895	3.986	V
		V_{AGND}	AGND	2 × Bandgap	2.522	2.602	2.685	V
		V_{REFLO}	Ref Low	Bandgap	1.255	1.301	1.350	V
0b100	RefPower = High Opamp bias = High	V_{REFHI}	Ref High	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.495 – P2[6]	2.586 – P2[6]	2.657 – P2[6]	V
		V_{AGND}	AGND	2 × Bandgap	2.502	2.604	2.719	V
		V_{REFLO}	Ref Low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.531 – P2[6]	2.611 – P2[6]	2.681 – P2[6]	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref High	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.500 – P2[6]	2.591 – P2[6]	2.662 – P2[6]	V
		V_{AGND}	AGND	2 × Bandgap	2.519	2.602	2.693	V
		V_{REFLO}	Ref Low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.530 – P2[6]	2.605 – P2[6]	2.666 – P2[6]	V
	RefPower = Med Opamp bias = High	V_{REFHI}	Ref High	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.503 – P2[6]	2.592 – P2[6]	2.662 – P2[6]	V
		V_{AGND}	AGND	2 × Bandgap	2.517	2.603	2.698	V
		V_{REFLO}	Ref Low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.529 – P2[6]	2.606 – P2[6]	2.665 – P2[6]	V
	RefPower = Med Opamp bias = Low	V_{REFHI}	Ref High	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.505 – P2[6]	2.594 – P2[6]	2.665 – P2[6]	V
		V_{AGND}	AGND	2 × Bandgap	2.525	2.602	2.685	V
		V_{REFLO}	Ref Low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.528 – P2[6]	2.603 – P2[6]	2.661 – P2[6]	V

Table 15. 3.3-V DC Analog Reference Specifications

Reference ARF_CR[5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Unit
0b000	RefPower = High Opamp bias = High	V_{REFHI}	Ref High	$V_{DD}/2$ + BandGap	$V_{DD}/2$ + 1.225	$V_{DD}/2$ + 1.292	$V_{DD}/2$ + 1.361	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.067	$V_{DD}/2$ – 0.002	$V_{DD}/2$ + 0.063	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – BandGap	$V_{DD}/2$ – 1.35	$V_{DD}/2$ – 1.293	$V_{DD}/2$ – 1.210	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref High	$V_{DD}/2$ + BandGap	$V_{DD}/2$ + 1.218	$V_{DD}/2$ + 1.294	$V_{DD}/2$ + 1.370	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.038	$V_{DD}/2$ – 0.001	$V_{DD}/2$ + 0.035	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – BandGap	$V_{DD}/2$ – 1.329	$V_{DD}/2$ – 1.296	$V_{DD}/2$ – 1.259	V
	RefPower = Med Opamp bias = High	V_{REFHI}	Ref High	$V_{DD}/2$ + BandGap	$V_{DD}/2$ + 1.221	$V_{DD}/2$ + 1.294	$V_{DD}/2$ + 1.366	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.050	$V_{DD}/2$ – 0.002	$V_{DD}/2$ + 0.046	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – BandGap	$V_{DD}/2$ – 1.331	$V_{DD}/2$ – 1.296	$V_{DD}/2$ – 1.260	V
	RefPower = Med Opamp bias = Low	V_{REFHI}	Ref High	$V_{DD}/2$ + BandGap	$V_{DD}/2$ + 1.226	$V_{DD}/2$ + 1.295	$V_{DD}/2$ + 1.365	V
		V_{AGND}	AGND	$V_{DD}/2$	$V_{DD}/2$ – 0.028	$V_{DD}/2$ – 0.001	$V_{DD}/2$ + 0.025	V
		V_{REFLO}	Ref Low	$V_{DD}/2$ – BandGap	$V_{DD}/2$ – 1.329	$V_{DD}/2$ – 1.297	$V_{DD}/2$ – 1.262	V
0b001	RefPower = High Opamp bias = High	V_{REFHI}	Ref High	P2[4]+P2[6] (P2[4] = $V_{DD}/2$, P2[6] = 0.5 V)	P2[4] + P2[6] – 0.098	P2[4] + P2[6] – 0.018	P2[4] + P2[6] + 0.055	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref Low	P2[4] – P2[6] (P2[4] = $V_{DD}/2$, P2[6] = 0.5 V)	P2[4] – P2[6] – 0.055	P2[4] – P2[6] + 0.013	P2[4] – P2[6] + 0.086	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref High	P2[4] + P2[6] (P2[4] = $V_{DD}/2$, P2[6] = 0.5 V)	P2[4] + P2[6] – 0.082	P2[4] + P2[6] – 0.011	P2[4] + P2[6] + 0.050	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref Low	P2[4] – P2[6] (P2[4] = $V_{DD}/2$, P2[6] = 0.5 V)	P2[4] – P2[6] – 0.037	P2[4] – P2[6] + 0.006	P2[4] – P2[6] + 0.054	V
	RefPower = Med Opamp bias = High	V_{REFHI}	Ref High	P2[4] + P2[6] (P2[4] = $V_{DD}/2$, P2[6] = 0.5 V)	P2[4] + P2[6] – 0.079	P2[4] + P2[6] – 0.012	P2[4] + P2[6] + 0.047	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref Low	P2[4]–P2[6] (P2[4] = $V_{DD}/2$, P2[6] = 0.5 V)	P2[4] – P2[6] – 0.038	P2[4] – P2[6] + 0.006	P2[4] – P2[6] + 0.057	V
	RefPower = Med Opamp bias = Low	V_{REFHI}	Ref High	P2[4]+P2[6] (P2[4] = $V_{DD}/2$, P2[6] = 0.5 V)	P2[4] + P2[6] – 0.080	P2[4] + P2[6] – 0.008	P2[4] + P2[6] + 0.055	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref Low	P2[4]–P2[6] (P2[4] = $V_{DD}/2$, P2[6] = 0.5 V)	P2[4] – P2[6] – 0.032	P2[4] – P2[6] + 0.003	P2[4] – P2[6] + 0.042	V

Table 15. 3.3-V DC Analog Reference Specifications (continued)

Reference ARF_CR[5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Unit
0b110	RefPower = High Opamp bias = High	V_{REFHI}	Ref High	2 × BandGap	2.507	2.598	2.698	V
		V_{AGND}	AGND	BandGap	1.203	1.307	1.424	V
		V_{REFLO}	Ref Low	Vss	Vss	Vss + 0.012	Vss + 0.067	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref High	2 × BandGap	2.516	2.598	2.683	V
		V_{AGND}	AGND	BandGap	1.241	1.303	1.376	V
		V_{REFLO}	Ref Low	Vss	Vss	Vss + 0.007	Vss + 0.040	V
	RefPower = Med Opamp bias = High	V_{REFHI}	Ref High	2 × BandGap	2.510	2.599	2.693	V
		V_{AGND}	AGND	BandGap	1.240	1.305	1.374	V
		V_{REFLO}	Ref Low	Vss	Vss	Vss + 0.008	Vss + 0.048	V
	RefPower = Med Opamp bias = Low	V_{REFHI}	Ref High	2 × BandGap	2.515	2.598	2.683	V
		V_{AGND}	AGND	BandGap	1.258	1.302	1.355	V
		V_{REFLO}	Ref Low	Vss	Vss	Vss + 0.005	Vss + 0.03	V
0b111	All power settings. Not allowed for 3.3 V.	–	–	–	–	–	–	–

DC Analog PSoC Block Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 16. DC Analog PSoC Block Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
R_{CT}	Resistor Unit Value (Continuous Time)	–	12.2	–	kΩ	
C_{SC}	Capacitor Unit Value (Switched Capacitor)	–	80	–	fF	

DC POR, SMP, and LVD Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 17. DC POR, SMP, and LVD Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
	V_{DD} Value for PPOR Trip (positive ramp)					
V_{PPOR0R}	PORLEV[1:0] = 00b		2.91		V	
V_{PPOR1R}	PORLEV[1:0] = 01b	–	4.39	–	V	
V_{PPOR2R}	PORLEV[1:0] = 10b		4.55		V	
	V_{DD} Value for PPOR Trip (negative ramp)					
V_{PPOR0}	PORLEV[1:0] = 00b		2.82		V	
V_{PPOR1}	PORLEV[1:0] = 01b	–	4.39	–	V	
V_{PPOR2}	PORLEV[1:0] = 10b		4.55		V	
	PPOR Hysteresis					
V_{PH0}	PORLEV[1:0] = 00b	–	92	–	mV	
V_{PH1}	PORLEV[1:0] = 01b	–	0	–	mV	
V_{PH2}	PORLEV[1:0] = 10b	–	0	–	mV	

Notes
4. Always greater than 50 mV above PPOR (PORLEV = 00) for falling supply.
5. Always greater than 50 mV above PPOR (PORLEV = 10) for falling supply.

Table 17. DC POR, SMP, and LVD Specifications (continued)

Symbol	Description	Min	Typ	Max	Units	Notes
	V_{DD} Value for LVD Trip					
V_{LVD0}	VM[2:0] = 000b	2.86	2.92	2.98[4]	V	
V_{LVD1}	VM[2:0] = 001b	2.96	3.02	3.08	V	
V_{LVD2}	VM[2:0] = 010b	3.07	3.13	3.20	V	
V_{LVD3}	VM[2:0] = 011b	3.92	4.00	4.08	V	
V_{LVD4}	VM[2:0] = 100b	4.39	4.48	4.57	V	
V_{LVD5}	VM[2:0] = 101b	4.55	4.64	4.74[5]	V	
V_{LVD6}	VM[2:0] = 110b	4.63	4.73	4.82	V	
V_{LVD7}	VM[2:0] = 111b	4.72	4.81	4.91	V	
					V	
	V_{DD} Value for SMP Trip					
V_{PUMP0}	VM[2:0] = 000b	2.96	3.02	3.08	V	
V_{PUMP1}	VM[2:0] = 001b	3.03	3.10	3.16	V	
V_{PUMP2}	VM[2:0] = 010b	3.18	3.25	3.32	V	
V_{PUMP3}	VM[2:0] = 011b	4.11	4.19	4.28	V	
V_{PUMP4}	VM[2:0] = 100b	4.55	4.64	4.74	V	
V_{PUMP5}	VM[2:0] = 101b	4.63	4.73	4.82	V	
V_{PUMP6}	VM[2:0] = 110b	4.72	4.82	4.91	V	
V_{PUMP7}	VM[2:0] = 111b	4.90	5.00	5.10	V	
					V	

DC Programming Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –-40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 18. DC Programming Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{DDP}	V_{DD} for programming and erase	4.5	5	5.5	V	This specification applies to the functional requirements of external programmer tools.
V_{DDLV}	Low V_{DD} for verify	3.0	3.1	3.2	V	This specification applies to the functional requirements of external programmer tools.
V_{DDHV}	High V_{DD} for verify	5.1	5.2	5.3	V	This specification applies to the functional requirements of external programmer tools.
$V_{DDIWRITE}$	Supply voltage for flash write operation	3.15	–	5.25	V	This specification applies to this device when it is executing internal flash writes.
I_{DDP}	Supply current during programming or verify	–	10	30	mA	
V_{ILP}	Input Low-voltage during programming or verify	–	–	0.8	V	
V_{IHP}	Input High-voltage during programming or verify	2.2	–	–	V	
I_{ILP}	Input Current when Applying V_{ILP} to P1[0] or P1[1] During Programming or Verify	–	–	0.2	mA	Driving internal pull-down resistor.
I_{IHP}	Input Current when Applying V_{IHP} to P1[0] or P1[1] During Programming or Verify	–	–	1.5	mA	Driving internal pull-down resistor.
V_{OLV}	Output Low-voltage during programming or verify	–	–	Vss + 0.75	V	
V_{OHV}	Output High-voltage during programming or verify	V_{DD} - 1.0	–	V_{DD}	V	
$Flash_{ENPB}$	flash endurance (per block)	50,000[6]	–	–	–	Erase/write cycles per block.
$Flash_{ENT}$	flash endurance (total)[7]	1,800,000	–	–	–	Erase/write cycles.
$Flash_{DR}$	flash data retention	10	–	–	Years	

DC I^2C Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 19. DC I^2C Specifications

Parameter	Description	Min	Typ	Max	Units	Notes
V_{ILI2C}[8]	Input low level	–	–	0.3 × V_{DD}	V	3.0 V ≤ V_{DD} ≤ 3.6 V
		–	–	0.25 × V_{DD}	V	4.75 V ≤ V_{DD} ≤ 5.25 V
V_{IHI2C}[8]	Input high level	0.7 × V_{DD}	–	–	V	3.0 V ≤ V_{DD} ≤ 5.25 V

Notes

6. The 50,000 cycle flash endurance per block is only guaranteed if the Flash is operating within one voltage range. Voltage ranges are 3.0 V to 3.6 V and 4.75 V to 5.25 V.
7. A maximum of 36 x 50,000 block endurance cycles is allowed. This may be balanced between operations on 36x1 blocks of 50,000 maximum cycles each, 36x2 blocks of 25,000 maximum cycles each, or 36x4 blocks of 12,500 maximum cycles each (to limit the total number of cycles to 36x50,000 and that no single block ever sees more than 50,000 cycles).
   For the full industrial range, the user must employ a temperature sensor user module (flashTemp) and feed the result to the temperature argument before writing. Refer to the Flash APIs Application Note AN2015 at http://www.cypress.com under Application Notes for more information.
8. All GPIOs meet the DC GPIO V_{IL} and V_{IH} specifications found in the DC GPIO specifications sections.The I^2C GPIO pins also meet the mentioned specs.

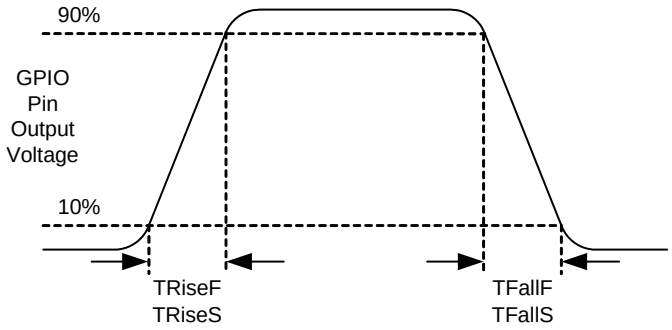
AC GPIO Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 21. AC GPIO Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
F_{GPIO}	GPIO operating frequency	0	–	12.3	MHz	Normal Strong Mode
TRiseF	Rise time, normal strong mode, Cload = 50 pF	3	–	18	ns	V_{DD} = 4.75 to 5.25 V, 10% - 90%
TFallF	Fall time, normal strong mode, Cload = 50 pF	2	–	18	ns	V_{DD} = 4.75 to 5.25 V, 10% - 90%
TRiseS	Rise time, slow strong mode, Cload = 50 pF	10	27	–	ns	V_{DD} = 3 to 5.25 V, 10% - 90%
TFallS	Fall time, slow strong mode, Cload = 50 pF	10	22	–	ns	V_{DD} = 3 to 5.25 V, 10% - 90%

Figure 10. GPIO Timing Diagram



AC Operational Amplifier Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Settling times, slew rates, and gain bandwidth are based on the Analog Continuous Time PSoC block.

Power = High and Opamp Bias = High is not supported at 3.3V.

Table 22. 5-V AC Operational Amplifier Specifications

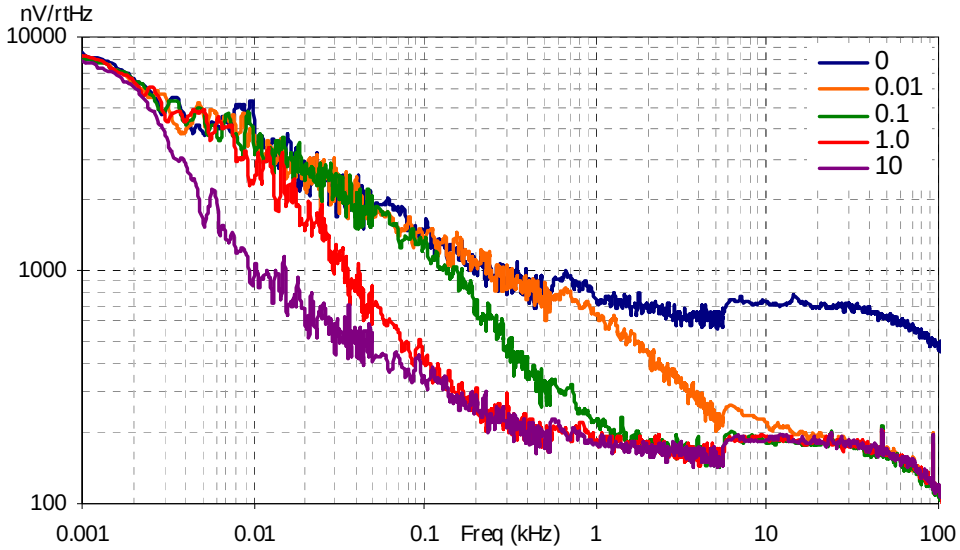
Symbol	Description	Min	Typ	Max	Units	Notes
T_{ROA}	Rising Settling Time to 0.1% for a 1 V Step (10 pF load, Unity Gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	 – – –	 – – –	 3.9 0.72 0.62	 µs µs µs	–
T_{SOA}	Falling Settling Time to 0.1% for a 1 V Step (10 pF load, Unity Gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	 – – –	 – – –	 5.9 0.92 0.72	 µs µs µs	–
SR_{ROA}	Rising Slew Rate (20% to 80%) of a 1 V Step (10 pF load, Unity Gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	 0.15 1.7 6.5	 – – –	 – – –	 V/µs V/µs V/µs	–
SR_{FOA}	Falling Slew Rate (20% to 80%) of a 1 V Step (10 pF load, Unity Gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	 0.01 0.5 4.0	 – – –	 – – –	 V/µs V/µs V/µs	–
BW_{OA}	Gain Bandwidth Product Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	 0.75 3.1 5.4	 – – –	 – – –	 MHz MHz MHz	–
E_{NOA}	Noise at 1 kHz (Power = Medium, Opamp Bias = High)	–	100	–	nV/rt-Hz	–

Table 23. 3.3-V AC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
T_{ROA}	Rising settling time to 0.1% of a 1 V Step (10 pF load, Unity Gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	 – –	 – –	 3.92 0.72	 µs µs	–
T_{SOA}	Falling settling time to 0.1% of a 1 V Step (10 pF load, Unity Gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	 – –	 – –	 5.41 0.72	 µs µs	–
SR_{ROA}	Rising Slew Rate (20% to 80%) of a 1 V Step (10 pF load, Unity Gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	 0.31 2.7	 – –	 – –	 V/µs V/µs	–
SR_{FOA}	Falling slew rate (20% to 80%) of a 1 V Step (10 pF load, Unity Gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	 0.24 1.8	 – –	 – –	 V/µs V/µs	–
BW_{OA}	Gain bandwidth product Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	 0.67 2.8	 – –	 – –	 MHz MHz	–
E_{NOA}	Noise at 1 kHz (Power = Medium, Opamp Bias = High)	–	100	–	nV/rt-Hz	–

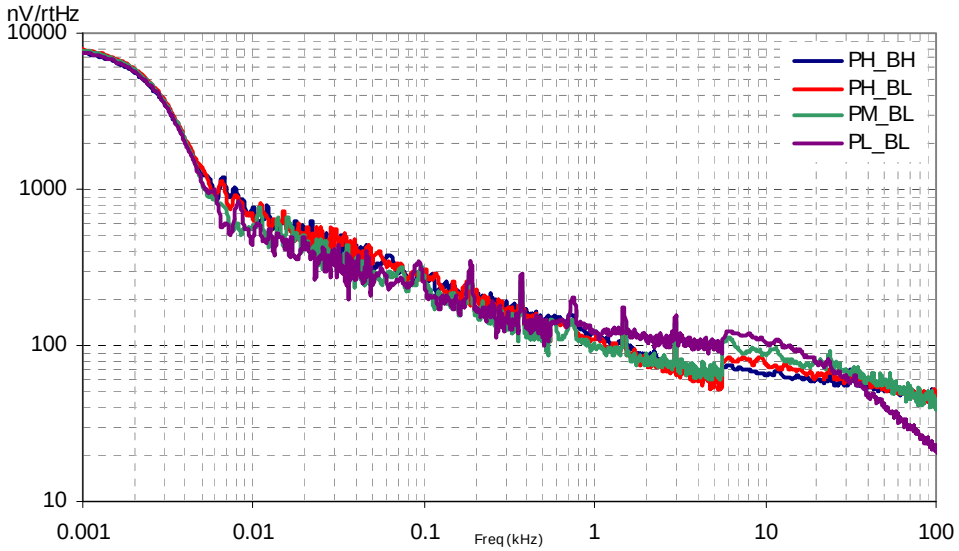
When bypassed by a capacitor on P2[4], the noise of the analog ground signal distributed to each block is reduced by a factor of up to 5 (14 dB). This is at frequencies above the corner frequency defined by the on-chip 8.1k resistance and the external capacitor.

Figure 11. Typical AGND Noise with P2[4] Bypass



At low frequencies, the opamp noise is proportional to 1/f, power independent, and determined by device geometry. At high frequencies, increased power level reduces the noise spectrum level.

Figure 12. Typical Opamp Noise



AC Programming Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and -40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and -40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 30. AC Programming Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
T_{RSCLK}	Rise Time of SCLK	1	–	20	ns	–
T_{FSCLK}	Fall Time of SCLK	1	–	20	ns	–
T_{SSCLK}	Data Set up Time to Falling Edge of SCLK	40	–	–	ns	–
T_{HSCLK}	Data Hold Time from Falling Edge of SCLK	40	–	–	ns	–
F_{SCLK}	Frequency of SCLK	0	–	8	MHz	–
T_{ERASEB}	flash Erase Time (Block)	–	10	–	ms	–
T_{WRITE}	flash Block Write Time	–	40	–	ms	–
T_{DSCLK}	Data Out Delay from Falling Edge of SCLK	–	–	45	ns	$V_{DD} > 3.6$
T_{DSCLK3}	Data Out Delay from Falling Edge of SCLK	–	–	50	ns	$3.0 \le V_{DD} \le 3.6$
$T_{ERASEALL}$	flash Erase Time (Bulk)	–	80	–	ms	Erase all blocks and protection fields at once.
$T_{PROGRAM\_HOT}$	flash Block Erase + flash Block Write Time	–	–	100[15]	ms	0°C ≤ T_J ≤ 100 °C
$T_{PROGRAM\_COLD}$	flash Block Erase + flash Block Write Time	–	–	200[15]	ms	-40°C ≤ T_J ≤ 0 °C

Note

15. For the full industrial range, the user must employ a Temperature Sensor User Module (flashTemp) and feed the result to the temperature argument before writing. Refer to the flash APIs Application Note AN2015 at http://www.cypress.com under Application Notes for more information.

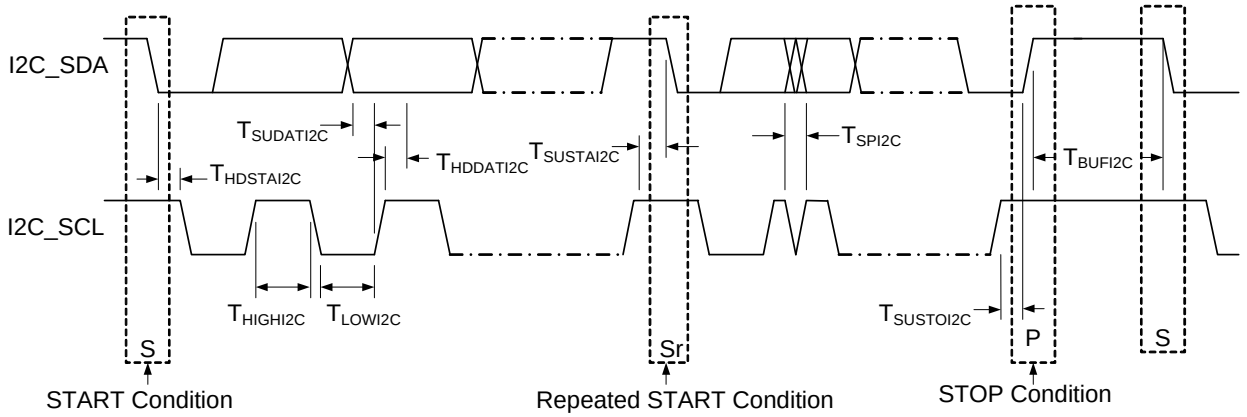
AC I²C Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and -40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and -40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 31. AC Characteristics of the I²C SDA and SCL Pins

Symbol	Description	Standard-Mode		Fast-Mode		Units	Notes
		Min	Max	Min	Max		
F_{SCLI2C}	SCL Clock Frequency	0	100	0	400	kHz	–
$T_{HDSTAI2C}$	Hold Time (repeated) START Condition. After this period, the first clock pulse is generated.	4.0	–	0.6	–	µs	–
T_{LOWI2C}	LOW Period of the SCL Clock	4.7	–	1.3	–	µs	–
$T_{HIGHI2C}$	HIGH Period of the SCL Clock	4.0	–	0.6	–	µs	–
$T_{SUSTAI2C}$	Set-up Time for a Repeated START Condition	4.7	–	0.6	–	µs	–
$T_{HDDATI2C}$	Data Hold Time	0	–	0	–	µs	–
$T_{SUDATI2C}$	Data Set-up Time	250	–	100[16]	–	ns	–
$T_{SUSTOI2C}$	Set-up Time for STOP Condition	4.0	–	0.6	–	µs	–
T_{BUFI2C}	Bus Free Time Between a STOP and START Condition	4.7	–	1.3	–	µs	–
T_{SPI2C}	Pulse Width of spikes are suppressed by the input filter.	–	–	0	50	ns	–

Figure 13. Definition for Timing for Fast-/Standard-Mode on the I²C Bus



Note

16. A Fast-Mode I2C-bus device can be used in a Standard-Mode I2C-bus system, but the requirement $t_{SU;DAT} \geq 250$ ns must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line $t_{rmax} + t_{SU;DAT} = 1000 + 250 = 1250$ ns (according to the Standard-Mode I2C-bus specification) before the SCL line is released.

Accessories (Emulation and Programming)

Table 35. Emulation and Programming Accessories

Part No.	Pin Package	Flex-Pod Kit[19]	Foot Kit[20]	Adapter[21]
CY8CLED16-48LFXI	48-pin QFN	CY3250-LED16QFN	CY3250-48QFN-FK	Adapters can be found at http://www.emulation.com.

Ordering Information

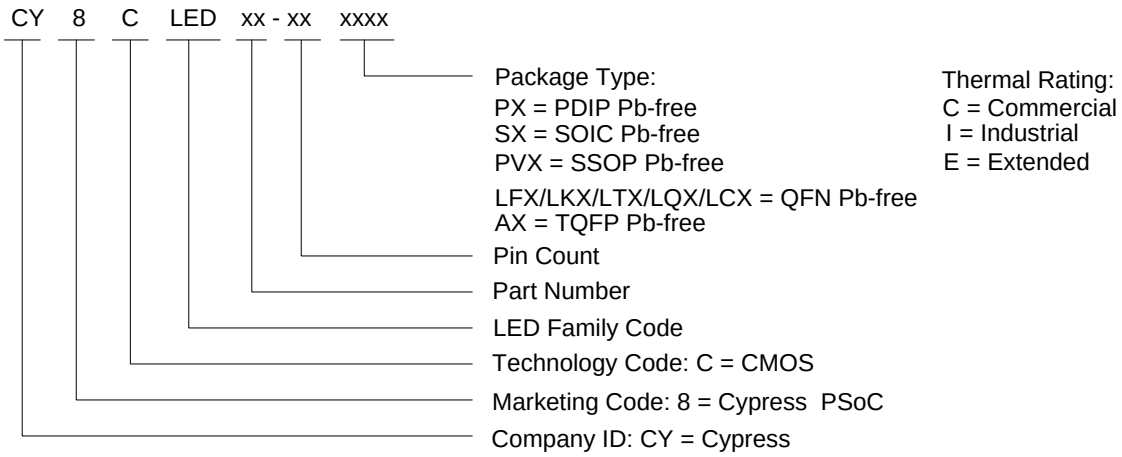
Key Device Features

The following table lists the CY8CLED16 EZ-Color devices' key package features and ordering codes.

Table 36. Device Key Features and Ordering Information

Package	Ordering Code	Flash (Bytes)	RAM (Bytes)	Switch Mode Pump	Temperature Range	Digital PSoC Blocks	Analog PSoC Blocks	Digital I/O Pins	Analog Inputs	Analog Outputs	XRES Pin
48-Pin QFN (Sawn)	CY8CLED16-48LTXI	32 K	2 K	Yes	–40 °C to +85 °C	16	12	44	12	4	Yes
48-Pin QFN (Tape and Reel) (Sawn)	CY8CLED16-48LTXIT	32 K	2 K	Yes	–40 °C to +85 °C	16	12	44	12	4	Yes

Ordering Code Definitions



Notes
19. Flex-Pod kit includes a practice flex-pod and a practice PCB, in addition to two flex-pods.
20. Foot kit includes surface mount feet that can be soldered to the target PCB.
21. Programming adapter converts non-DIP package to DIP footprint. Specific details and ordering information for each of the adapters can be found at http://www.emulation.com.

Acronyms

Acronyms Used

Table 37 lists the acronyms that are used in this document.

Table 37. Acronyms Used in this Datasheet

Acronym	Description	Acronym	Description
AC	alternating current	MAC	multiply-accumulate
ADC	analog-to-digital converter	MIPS	million instructions per second
API	application programming interface	PCB	printed circuit board
CMOS	complementary metal oxide semiconductor	PDIP	plastic dual-in-line package
CPU	central processing unit	PLL	phase-locked loop
CRC	cyclic redundancy check	POR	power-on reset
CT	continuous time	PPOR	precision power on reset
DAC	digital-to-analog converter	PRS	pseudo-random sequence
DC	direct current	PSoC®	Programmable System-on-Chip
DTMF	dual-tone multi-frequency	PWM	pulse-width modulator
ECO	external crystal oscillator	QFN	quad flat no leads
EEPROM	electrically erasable programmable read-only memory	RTC	real time clock
GPIO	general purpose I/O	SAR	successive approximation
ICE	in-circuit emulator	SC	switched capacitor
IDE	integrated development environment	SMP	switch mode pump
ILO	internal low speed oscillator	SPI	serial peripheral interface
IMO	internal main oscillator	SRAM	static random access memory
I/O	input/output	SROM	supervisory read only memory
IrDA	infrared data association	SSOP	shrink small-outline package
ISSP	in-system serial programming	UART	universal asynchronous reciever / transmitter
LCD	liquid crystal display	USB	universal serial bus
LED	light-emitting diode	WDT	watchdog timer
LPC	low power comparator	XRES	external reset
LVD	low-voltage detect		

Reference Documents

Design Aids – Reading and Writing PSoC® Flash – AN2015 (001-40459)

Understanding Datasheet Jitter Specifications for Cypress Timing Products – AN5054 (001-14503)

Application Notes for Surface Mount Assembly of Amkor's MicroLeadFrame (MLF) Packages – available at http://www.amkor.com.

Document Conventions

Units of Measure

Table 38 lists the units of measures.

Table 38. Units of Measure

Symbol	Unit of Measure	Symbol	Unit of Measure
dB	decibels	ms	milliseconds
°C	degree Celsius	mH	millihenry
fF	femtofarad	ns	nanoseconds
kHz	kilohertz	µV	microvolts
kΩ	kilohm	V	volts
MHz	megahertz	mV	millivolts
µA	microamperes	µW	microwatts
µs	microseconds	%	percent
mA	milliamperes	W	watt
nA	nanoamperes	mm	millimeters
pF	picofarad	ps	picosecond
pA	pikoamperes	ppm	parts per million
rt-Hz	root hertz	nV	nanovolts

Numeric Conventions

Hexadecimal numbers are represented with all letters in uppercase with an appended lowercase ‘h’ (for example, ‘14h’ or ‘3Ah’). Hexadecimal numbers may also be represented by a ‘0x’ prefix, the C coding convention. Binary numbers have an appended lowercase ‘b’ (for example, 01010100b’ or ‘01000011b’). Numbers not indicated by an ‘h’, ‘b’, or 0x are decimals.

Glossary

active high	1. A logic signal having its asserted state as the logic 1 state. 2. A logic signal having the logic 1 state as the higher voltage of the two states.
analog blocks	The basic programmable opamp circuits. These are switched capacitor (SC) and continuous time (CT) blocks. These blocks can be interconnected to provide ADCs, DACs, multi-pole filters, gain stages, and much more.
analog-to-digital (ADC)	A device that changes an analog signal to a digital signal of corresponding magnitude. Typically, an ADC converts a voltage to a digital number. The digital-to-analog (DAC) converter performs the reverse operation.
Application programming interface (API)	A series of software routines that comprise an interface between a computer application and lower level services and functions (for example, user modules and libraries). APIs serve as building blocks for programmers that create software applications.
asynchronous	A signal whose data is acknowledged or acted upon immediately, irrespective of any clock signal.
bandgap reference	A stable voltage reference design that matches the positive temperature coefficient of VT with the negative temperature coefficient of VBE, to produce a zero temperature coefficient (ideally) reference.
bandwidth	1. The frequency range of a message or information processing system measured in hertz. 2. The width of the spectral region over which an amplifier (or absorber) has substantial gain (or loss); it is sometimes represented more specifically as, for example, full width at half maximum.

Document History Page

Document Title: CY8CLED16 EZ-Color™ HB LED Controller Document Number: 001-13105				
Revision	**ECN No**	**Origin of Change**	**Submission Date**	**Description of Change**
**	1148504	SFVTMP3	See ECN	New document (revision **).
*A	2763950	DPT	09/29/2009	Added 48QFN package diagram (Sawn). Added Saw Marketing part number in ordering information.
*B	2794355	XBM	10/28/2009	Added "Contents" on page 3 Updated "Development Tools" on page 7. Corrected FCPU1 and FCPU2 parameters in "AC Chip-Level Specifications" on page 31.
*C	2850593	FRE	01/14/2010	Updated DC GPIO, AC Chip-Level, and AC Programming Specifications as follows: Replaced TRAMP (time) with SRPOWER_UP (slew rate) specification. Added note to flash Endurance specification. Added IOH, IOL, DCILO, F32K_U, TPOWERUP, TERASEALL, TPROGRAM_HOT, and TPROGRAM_COLD specifications. Corrected the Pod Kit part numbers. Updated Development Tool Selection. Updated copyright and Sales, Solutions, and Legal Information URLs. Updated 28-Pin SSOP 48-Pin QFN (Punched), 48-Pin QFN (Sawn) package diagrams. Removed Preliminary for Final status.
*D	2896238	CGX	03/19/10	Updated ordering information table. Removed part numbers CY8CLED16-48LFXI and CY8CLED16-48LFXIT Updated copyright section. Updated package diagram for spec 51-85061
*E	2903043	NJF	04/01/2010	Updated Cypress website links Added $T_{BAKETEMP}$ and $T_{BAKETIME}$ parameters Removed reference to 2.4V Removed sections "Third Party Tools" and "Build a PSoC Emulator"
*F	3054665	CGX	10/11/2010	Removed pruned parts CY8CLED16-48PVXI and CY8CLED16-48PVXIT
*G	3114959	NJF	12/19/10	Added DC I^2C Specifications table. Added F_{32K_U} max limit. Added Tjit_IMO specification, removed existing jitter specifications. Updated DC Analog reference, DC operational amplifier specifications and DC analog output buffer specifications tables. Updated Units of Measure, Acronyms, Glossary, and References sections. Updated solder reflow specifications. No specific changes were made to AC Digital Block Specifications table and I^2C Timing Diagram. They were updated for clearer understanding. Updated Figure 12 since the labelling for y-axis was incorrect. Removed footnote reference for "Solder Reflow Peak Temperature" table.
*H	3284932	SHOB	06/24/11	Updated Getting Started, Development Tools, and Designing with PSoC Designer. Removed drawings and references to 48-Pin QFN (Punched) and 48-Pin SSOP. Removed obsolete kits. Removed reference to obsolete spec AN2012.
*I	3403622	10/12/11	MKKU	Removed the following pruned parts from the Ordering Information and Accessories (Emulation and Programming) sections. CY8CLED16-28PVXI CY8CLED16-28PVXIT